



# SCHOTTKY RECTIFIERS

## MAIN PRODUCT CHARACTERISTICS

I <sub>F(AV)</sub>	0.5 A
V <sub>RRM</sub>	20 V
V <sub>F</sub> (max)	0.32 V

## **FEATURES AND BENEFITS**

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING

#### **DESCRIPTION**

Single Schottky rectifier suited for switch mode power supplies and high frequency DC to DC converters.

Packaged in SOD-123, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications. Due to the small size of the package this device fits GSM and PCMCIA requirements.



# **ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter	Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage	20	V
I <sub>F(RMS)</sub>	RMS forward current	2	А
I <sub>F(AV)</sub>	Average forward current $\delta$ =0.5	0.5	А
I <sub>FSM</sub>	Surge non repetitive forward current	5.5	А
dV/dt	Critical rate of rise of reverse voltage	10000	V/μs
T <sub>stg</sub>	Storage temperature range	- 65 to + 125	°C
Tj	Maximum operating junction temperature *	125	°C
TL	Maximum temperature for soldering during 10s	260	°C

\* :  $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  thermal runaway condition for a diode on its own heatsink

January 2002 - Ed : 2B

# **STPS0520Z**

# THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R <sub>th (j-a)</sub>	Junction to ambient	430 (*)	°C/W
		210 (**)	

<sup>(\*)</sup> Mounted on epoxy board with recommended Pad Layout.

# STATIC ELECTRICAL CHARACTERISTICS

			Va	lue		
Symbol	Parameter	Tests conditions		STPS	0520Z	Unit
			typ.	max.		
I <sub>R</sub> *	Reverse leakage current	Tj = 25°C	V <sub>R</sub> = 10 V		60	μΑ
		Tj = 100°C		2.5	5	mA
		Tj = 25°C	$V_R = V_{RRM}$		150	μΑ
		Tj = 100°C		4.3	8	mA
V <sub>F</sub> **	Forward voltage drop	Tj = 25°C	I <sub>F</sub> = 0.1 A		0.3	V
		Tj = 100°C		0.18	0.22	
		Tj = 25°C	I <sub>F</sub> = 0.5 A		0.385	
		Tj=100°C		0.29	0.32	

Pulse test :  $* tp = 5 ms, \delta < 2\%$ \*\*  $tp = 380 \,\mu s$ ,  $\delta < 2\%$ 

To evaluate the maximum conduction losses use the following equation : P = 0.23 x  $I_{F(AV)}$  + 0.18 x  $I_{F}^{2}_{(RMS)}$ 

<sup>(\*\*)</sup> Mounted on epoxy board with 50mm2 copper area.

**Fig. 1:** Average forward power dissipation versus average forward current

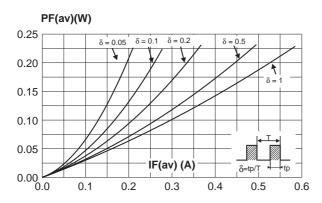
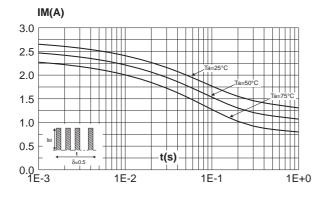


Fig. 3: Non repetitive surge peak forward current versus overload duration (maximum values).



**Fig. 5:** Reverse leakage current versus reverse voltage applied (typical values).

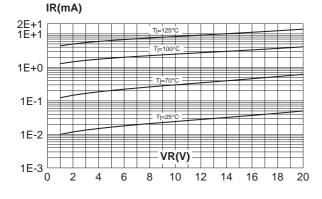
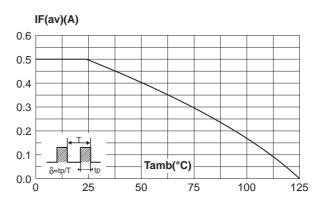
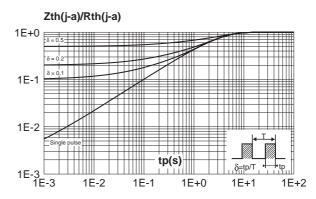


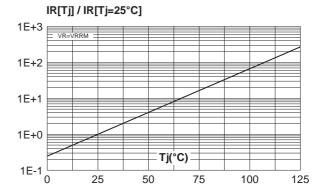
Fig. 2: Average forward current versus ambient temperature ( $\delta = 0.5$ )



**Fig. 4:** Relative variation of thermal impedance junction to ambient versus pulse duration (Epoxy printed circuit board FR4 with recommended pad layout).



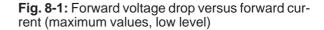
**Fig. 6:** Relative variation of reverse leakage current versus junction temperature (typical values).

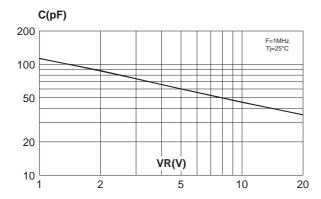


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Fig. 7: Junction capacitance versus reverse voltage applied (typical values).





IFM(A)

0.5

0.4

0.7

Tj=100°C

Typical values /

0.2

0.1

0.0

0.0

0.1

0.0

0.0

0.1

0.0

0.0

0.1

0.2

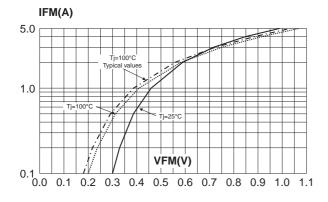
0.3

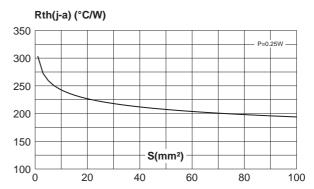
0.4

0.5

Fig. 8-2: Forward voltage drop versus forward current (maximum values, high level)

**Fig. 9:** Variation of thermal resistance junction to ambient versus copper surface under each lead (Printed circuit board FR4,  $e(Cu) = 35\mu m$ ).

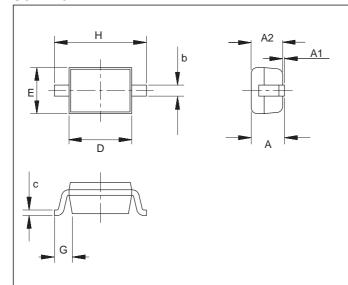




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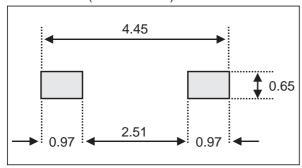
## **PACKAGE MECHANICAL DATA**

SOD-123



	DIMENSIONS				
REF.	Millimeters Min. Max.		Inches		
			Min.	Max.	
Α		1.45		0.057	
A1	0	0.1	0	0.004	
A2	0.85	1.35	0.033	0.053	
b	0.55 Typ.		0.022 Typ.		
С	0.15 Typ.		0.039 Typ.		
D	2.55	2.85	0.1	0.112	
E	1.4	1.7	0.055	0.067	
G	0.25		0.01		
Н	3.55	3.95	0.14	0.156	

## **FOOTPRINT** (in millimeters)



## **MARKING**

Туре	Marking	Package	Weight	Base qty	Delivery mode
STPS0520Z	Z52	SOD-123	0.01g.	3000	Tape & reel
STPS0520Z10K	Z52	SOD-123	0.01 g	10000	Tape & reel

- Epoxy meets UL94, V0.
- Band indicates cathode.

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